

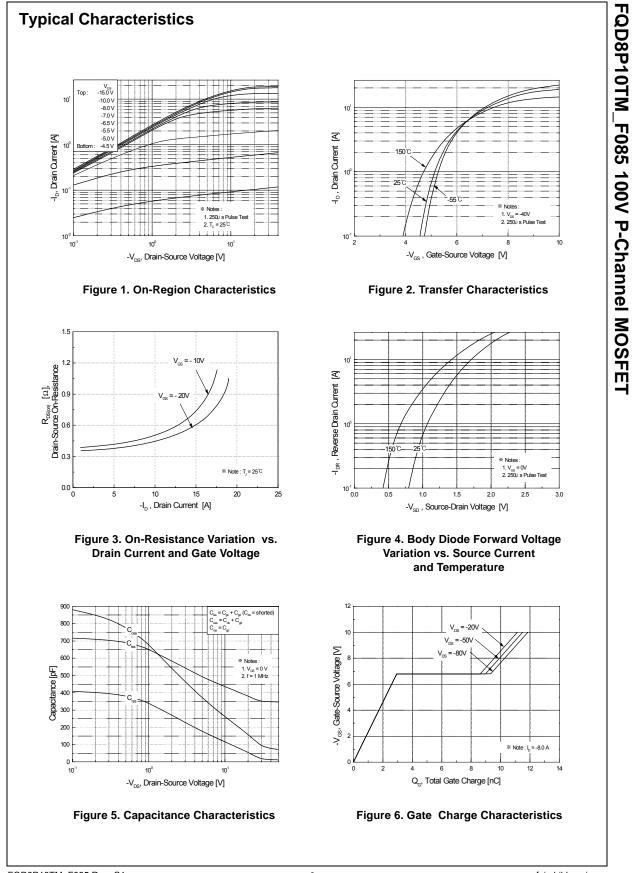
Symbol	Parameter		Ratings		Units
V _{DSS}	Drain-Source Voltage		-100		V
I _D	Drain Current - Continuous ($T_C = 25^{\circ}C$)		-6.6		А
	- Continuous (T _C = 100°C)		-4.2		А
I _{DM}	Drain Current - Pulsed (Note 1)		-26.4		А
V _{GSS}	Gate-Source Voltage		± 30		V
E _{AS}	Single Pulsed Avalanche Energy (Note 2) 150		50	mJ	
I _{AR}	Avalanche Current (Note 1)		-6	.6	А
E _{AR}	Repetitive Avalanche Energy	(Note 1)	4	.4	mJ
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	-6	.0	V/ns
P _D	Power Dissipation ($T_A = 25^{\circ}C$) *		2.5		W
	Power Dissipation ($T_C = 25^{\circ}C$)		4	4	W
	- Derate above 25°C		0.35		W/°C
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +150		°C
TL	Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds		300		°C
hermal	Characteristics				
Symbol	Parameter		Тур	Max	Units
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case			2.84	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction-to-Ambient *			50	°C/W
R _{θJA}	Thermal Resistance, Junction-to-Ambient			110	°C/W

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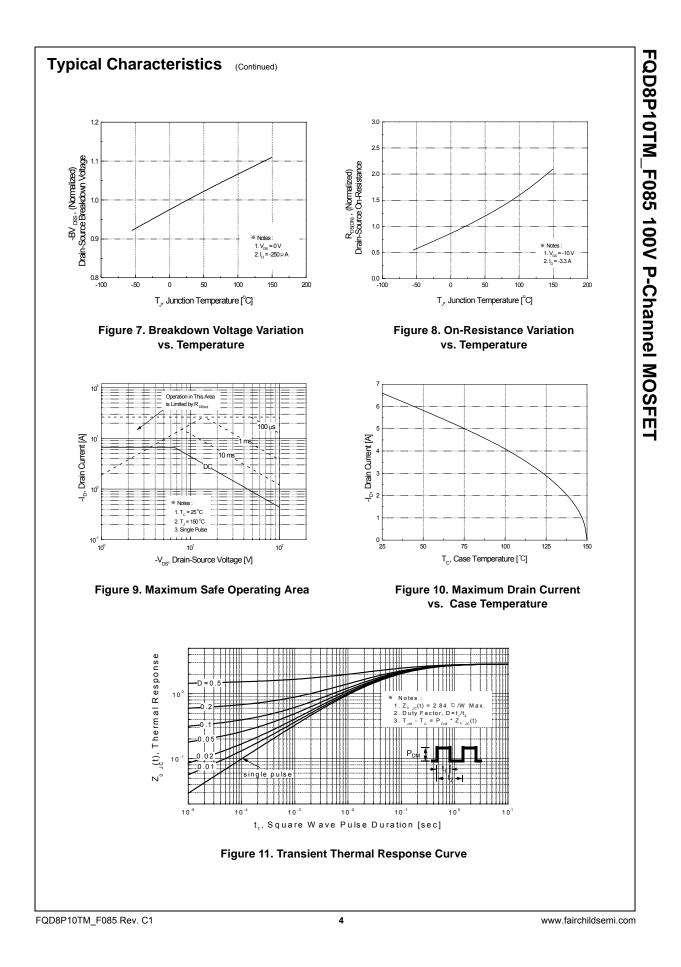
ΔBV _{DSS} Bre / ΔT _J Co I _{DSS} Zel I _{GSSF} Ga	eakdown Voltage Temperature befficient	V_{GS} = 0 V, I _D = -250 μA I _D = -250 μA, Referenced to 25°C				
BV _{DSS} Dra ΔBV _{DSS} Bre / ΔT _J Co I _{DSS} Zer I _{GSSF} Ga	ain-Source Breakdown Voltage eakdown Voltage Temperature pefficient					
ΔBV _{DSS} Bre / ΔT _J Co I _{DSS} Zel I _{GSSF} Ga	eakdown Voltage Temperature efficient		-100			V
I _{DSS} Zel				-0.1		V/°C
I _{GSSF} Ga	to cate vehage Brain carrent	V _{DS} = -100 V, V _{GS} = 0 V			-1	μA
		V _{DS} = -80 V, T _C = 125°C			-10	μA
I _{GSSR} Ga	te-Body Leakage Current, Forward	V_{GS} = -30 V, V_{DS} = 0 V			-100	nA
	ate-Body Leakage Current, Reverse	V_{GS} = 30 V, V_{DS} = 0 V			100	nA
On Charac	toristics					
	ite Threshold Voltage	V _{DS} = V _{GS} , I _D = -250 μA	-2.0		-4.0	V
R _{DS(on)} Sta	atic Drain-Source	$V_{GS} = -10 \text{ V}, \text{ I}_{D} = -3.3 \text{ A}$		0.41	0.53	Ω
	rward Transconductance	V _{DS} = -40 V, I _D = -3.3 A (Note 4)		4.1		S
9F5 10				7.1		Ŭ
Dynamic C	Characteristics					
C _{iss} Inp	out Capacitance	V _{DS} = -25 V, V _{GS} = 0 V,		360	470	pF
C _{oss} Ou	Itput Capacitance	f = 1.0 MHz		120	155	pF
C _{rss} Re	verse Transfer Capacitance			30	40	pF
0						
	Characteristics			11	20	-
=(=)	rn-On Delay Time	V _{DD} = -50 V, I _D = -8.0 A,		11	30	ns
	rn-On Rise Time	R _G = 25 Ω		110	230	ns
u(0)	rn-Off Delay Time rn-Off Fall Time	(Note 4, 5)		20 35	50 80	ns
						ns
3	tal Gate Charge	$V_{\rm DS}$ = -80 V, $I_{\rm D}$ = -8.0 A,		12	15 	nC
3-	ate-Source Charge	V _{GS} = -10 V (Note 4, 5)		3.0 6.4		nC nC
	rce Diode Characteristics ar	nd Maximum Ratings		0.1		
-	aximum Continuous Drain-Source Dic				-6.6	Α
	aximum Pulsed Drain-Source Diode F	Forward Current			-26.4	Α
0						V
	everse Recovery Time			98		ns
-		$dI_{\rm F} / dt = 100 \text{ A/}\mu \text{s}$ (Note 4)		0.35		μC
I _{SM} Ma	aximum Pulsed Drain-Source Diode F ain-Source Diode Forward Voltage	$V_{GS} = 0 V, I_S = -6.6 A$ $V_{GS} = 0 V, I_S = -8.0 A,$				r

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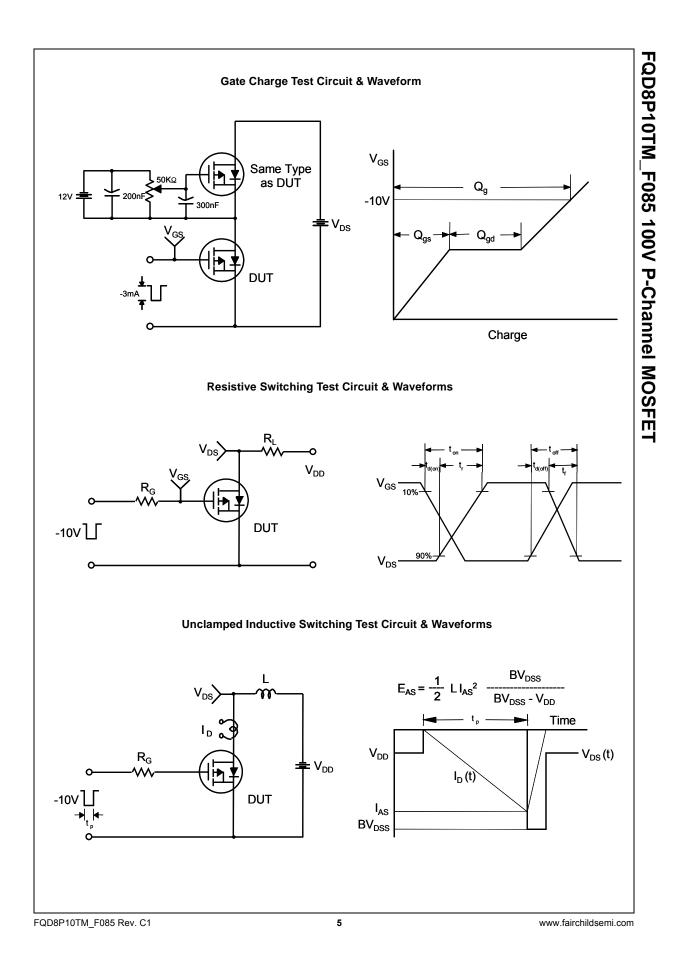
FQD8P10TM_F085 100V P-Channel MOSFET

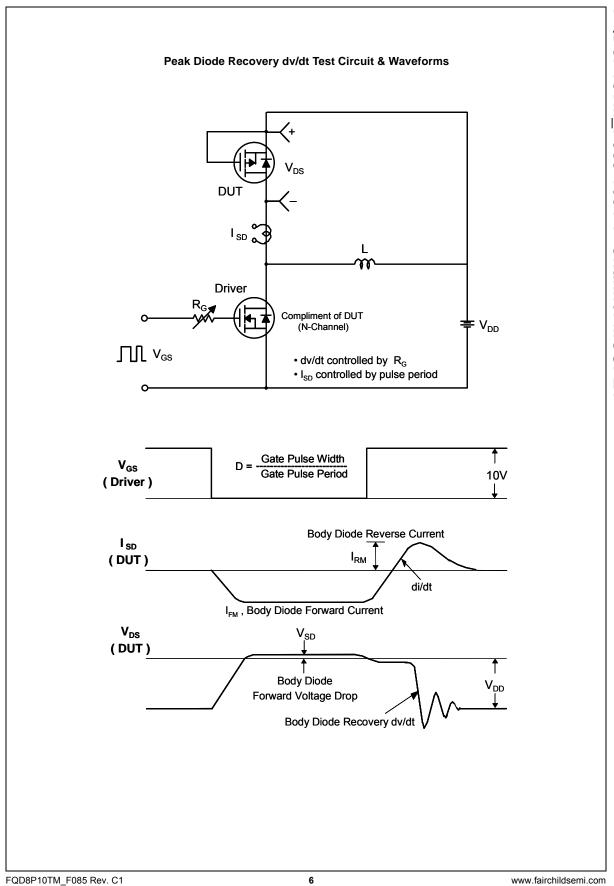


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